imall

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IGBT

This Insulated Gate Bipolar Transistor (IGBT) features a robust and cost effective Trench construction, and provides superior performance in demanding switching applications, offering both low on state voltage and minimal switching loss.

Features

- Low Saturation Voltage using Trench with Field Stop Technology
- Low Switching Loss Reduces System Power Dissipation
- Optimized for High Speed Switching
- 5 µs Short–Circuit Capability
- These are Pb–Free Devices

Typical Applications

- Power Factor Correction
- Solar Inverters
- Uninterruptable Power Supply (UPS)

ABSOLUTE MAXIMUM RATINGS

Symbol	Value	Unit
-		
V _{CES}	600	V
I _C	60 30	A
I _{CM}	120	A
Ι _F	60 30	A
I _{FM}	120	A
t _{SC}	5	μs
V _{GE}	±20 ±30	V
P _D	250 67	W
ТJ	–55 to +150	°C
T _{stg}	–55 to +150	°C
T _{SLD}	260	°C
	I _{CM} I _F I _{FM} t _{SC} V _{GE} V _{GE} T _J T _{stg}	V _{CES} 600 I _C 60 I _C 60 I _C 60 I _C 120 I _F 60 I _F 5 V _{GE} ± 20 ± 30 ± 30 P _D 250 67 7 T _J -55 to +150 T _{stg} -55 to +150

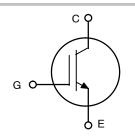
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

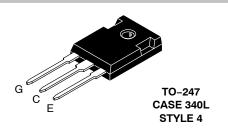


ON Semiconductor®

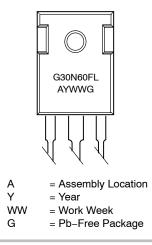
http://onsemi.com

30 A, 600 V V_{CEsat} = 1.65 V





MARKING DIAGRAM



ORDERING INFORMATION

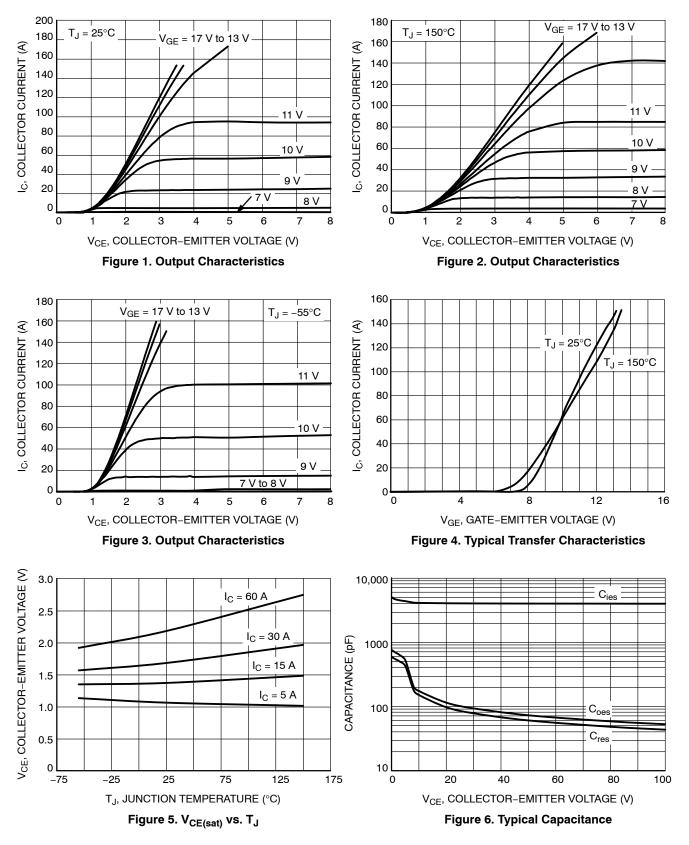
Device	Package	Shipping
NGTG30N60FLWG	TO–247 (Pb–Free)	30 Units / Rail

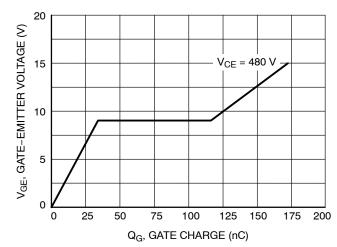
THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Thermal resistance junction-to-case, for IGBT	$R_{ ext{ heta}JC}$	0.486	°C/W
Thermal resistance junction-to-ambient	$R_{\theta JA}$	40	°C/W

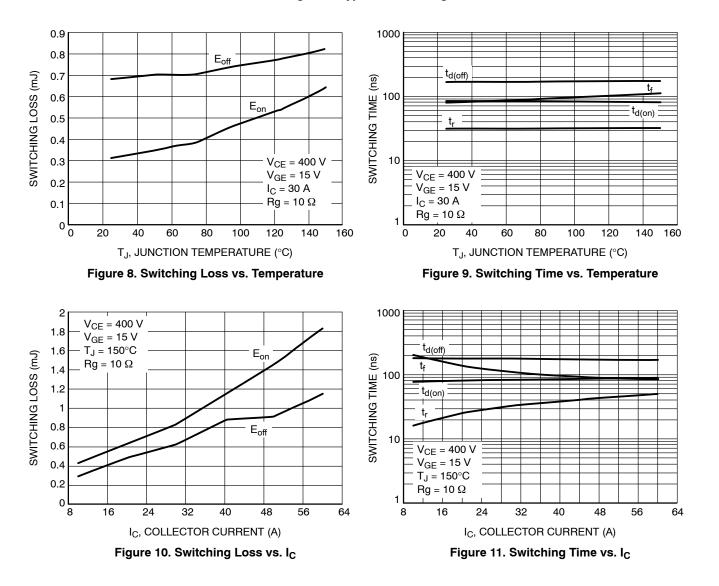
ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise specified)

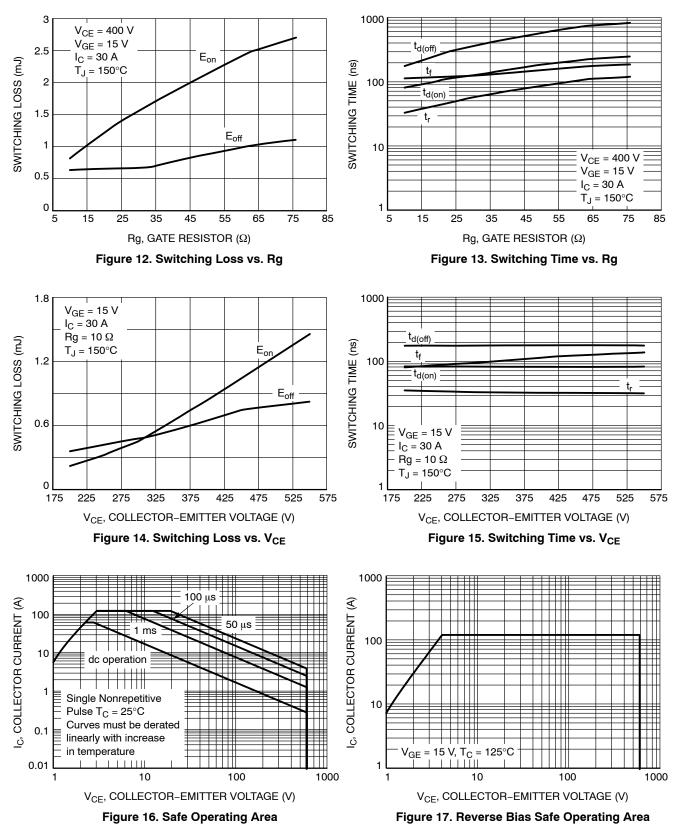
Parameter	Test Conditions	Symbol	Min	Тур	Max	Unit
STATIC CHARACTERISTIC	·					
Collector-emitter breakdown voltage, gate-emitter short-circuited	V_{GE} = 0 V, I _C = 500 µA	V _{(BR)CES}	600	-	_	V
Collector-emitter saturation voltage	$V_{GE} = 15 \text{ V}, \text{ I}_{C} = 30 \text{ A}$ $V_{GE} = 15 \text{ V}, \text{ I}_{C} = 30 \text{ A}, \text{ T}_{J} = 150^{\circ}\text{C}$	V _{CEsat}	1.4 _	1.65 2.0	1.9 _	V
Gate-emitter threshold voltage	V_{GE} = V_{CE} , I_C = 200 μ A	V _{GE(th)}	4.5	5.5	6.5	V
Collector-emitter cut-off current, gate- emitter short-circuited	$\label{eq:VGE} \begin{array}{c} V_{GE} = 0 \ V, \ V_{CE} = 600 \ V \\ V_{GE} = 0 \ V, \ V_{CE} = 600 \ V, \ T_{J} = 150^{\circ} C \end{array}$	I _{CES}	-		0.2 2	mA
Gate leakage current, collector-emitter short-circuited	V_{GE} = 20 V , V_{CE} = 0 V	I _{GES}	-	-	100	nA
DYNAMIC CHARACTERISTIC	•					
Input capacitance		C _{ies}	-	4200	-	pF
Output capacitance	V _{CE} = 20 V, V _{GE} = 0 V, f = 1 MHz	C _{oes}	-	130	-	
Reverse transfer capacitance	1	C _{res}	-	110	-	
Gate charge total		Qg	-	170	-	nC
Gate to emitter charge	V_{CE} = 480 V, I _C = 30 A, V _{GE} = 15 V	Q _{ge}	-	34	-	
Gate to collector charge		Q _{gc}	-	83	-	
SWITCHING CHARACTERISTIC, INDUC	TIVE LOAD					
Turn-on delay time		t _{d(on)}	-	83	-	ns
Rise time	1	tr	-	31	-	
Turn-off delay time	T.I = 25°C	t _{d(off)}	-	170	-	
Fall time	V_{CC} = 400 V, I _C = 30 A R _g = 10 Ω	t _f	-	80	-	
Turn-on switching loss	$V_{GE} = 0 V/15 V$	E _{on}	-	0.7	-	mJ
Turn-off switching loss	-	E _{off}	-	0.28	-	
Total switching loss		E _{ts}	-	0.98	-	
Turn-on delay time	$T_{J} = 150^{\circ}C$ $V_{CC} = 400 \text{ V}, I_{C} = 30 \text{ A}$ $R_{g} = 10 \Omega$ $V_{GE} = 0 \text{ V}/ 15 \text{ V}$	t _{d(on)}	-	81	-	ns
Rise time		tr	-	32	-	-
Turn-off delay time		t _{d(off)}	-	180	-	
Fall time		t _f	-	110	-	
Turn-on switching loss		Eon	-	0.82	-	mJ
Turn-off switching loss		E _{off}	-	0.63	-]
Total switching loss		E _{ts}	-	1.45	-	











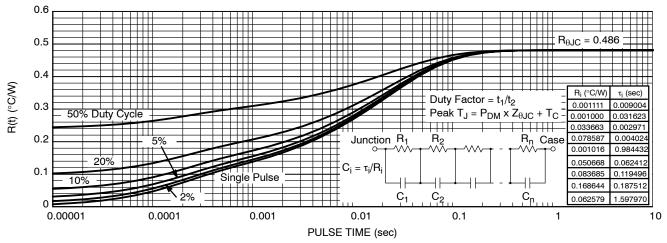


Figure 18. IGBT Transient Thermal Impedance

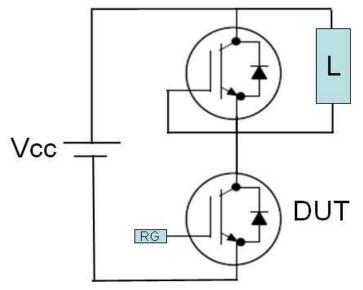
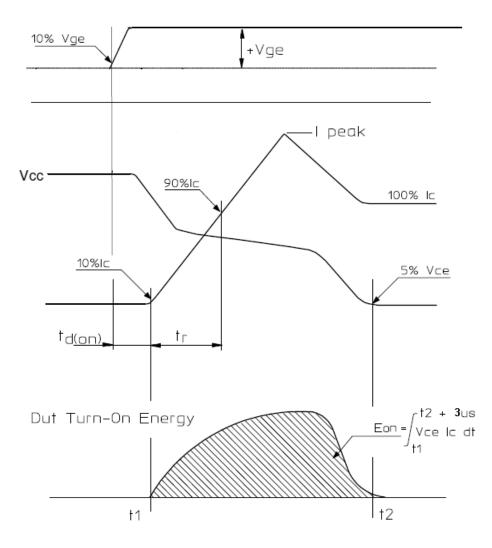
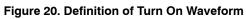


Figure 19. Test Circuit for Switching Characteristics





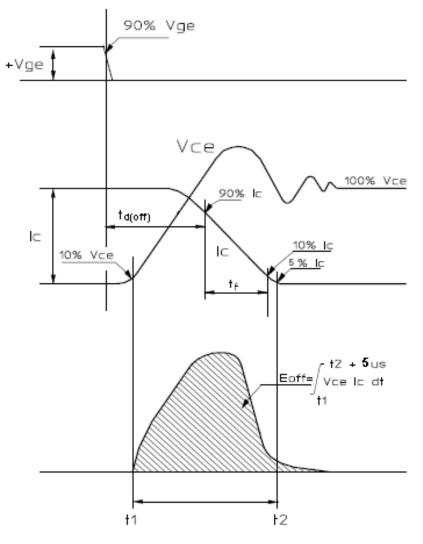
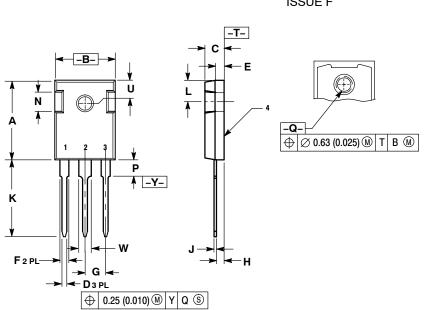


Figure 21. Definition of Turn Off Waveform

PACKAGE DIMENSIONS



TO-247 CASE 340L-02 ISSUE F

> Y14.5M, 1982 2. CONTROLLING DIMENSION: MILLIMETER. MILLIMETERS INCHES DIM MIN MAX MIN MAX 20.32 21.08 0.800 8.30 Α в 15.75 16.26 0.620 0.640 C 5.30 0.185 0.209 4.70 D 1.40 0.040 0.055 1.00 1.90
> 2.60
> 0.075
> 0.102
>
>
> 2.13
> 0.065
> 0.084
> E F 1.65 G 5.45 BSC 0.215 BSC Н 1.50 2.49 0.059 0.098 J 0.40 0.80 0.016 0.031 K 19.81 20.83 0.780 0.820 6.20 0.212 0.244 5.40 Ν 5.49 0.170 0.216 4.32 Р 4.50 0.177 3.55 3.65 0.140 0.144 Q U 6.15 BSC 0.242 BSC 2.87 3.12 0.113 0.123 w 2.87

1. DIMENSIONING AND TOLERANCING PER ANSI

STYLE 4: PIN 1. GATE

NOTES:

2. COLLECTOR 3. EMITTER

4. COLLECTOR

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